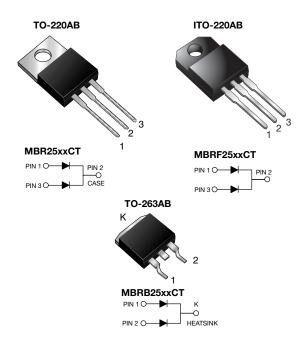
MBR25xxCT, MBRF25xxCT, MBRB25xxCT

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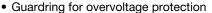
Dual Common Cathode Schottky Rectifier



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 12.5 A				
V _{RRM} 35 V to 60 V					
I _{FSM}	150 A				
V_{F}	0.73 V at 30 A, 0.65 V at 15 A				
T _J max. 150 °C					
Package	TO-220AB, ITO-220AB, TO-263AB				
Diode variations	Common cathode				

FEATURES

Power pack



- · Lower power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- · High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AB and ITO-220AB package)
- Material categorization: For definitions of compliance please see <u>www.vishav.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, or polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB
Epoxy meets UL 94 V-0 flammability rating
Base P/N-E3 - RoHS-compliant, commercial grade
Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix

meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)							
PARAMETER		SYMBOL	MBR2535CT	MBR2545CT	MBR2550CT	MBR2560CT	UNIT
Maximum repetitive peak reverse voltage		V_{RRM}	35	45	50	60	
Working peak reverse voltage		V_{RWM}	35	45	50	60	V
Maximum DC blocking voltage		V_{DC}	35	45	50	60	İ
Maximum average forward rectified current	total device		25				
at $T_C = 130 ^{\circ}C$	per diode	I _{F(AV)}	12.5				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	150				Α
Peak repetitive reverse surge current per diode at $t_p = 2 \mu s$, 1 kHz		I _{RRM}	1.0 0.5		.5		
Peak non-repetitive reverse energy (8/20 μs waveform) per diode		E _{RSM}	25				mJ
Electrostatic discharge capacitor voltage human body model: C = 100 pF, R = 1.5 k Ω		V _C	25				kV
Voltage rate of change (rated V _R)		dV/dt	10 000			V/µs	
Operating junction temperature range		TJ	- 65 to + 150			°C	
Storage temperature range		T _{STG}	- 65 to + 175				
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V _{AC}	1500			V	



MBR25xxCT, MBRF25xxCT, MBRB25xxCT

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ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	MBR2535CT	MBR2545CT	MBR2550CT	MBR2560CT	UNIT
Maximum instantaneous forward voltage per diode	I _E = 15 A	T _C = 25 °C	V _F ⁽¹⁾	-		0.75		V
	IF = 13 A	T _C = 125 °C		-		0.65		
	I _F = 30 A	T _C = 25 °C		0.82		-		
	IF = 30 A	T _C = 125 °C		0.73		-		
Maximum instantaneous reverse current at blocking voltage per diode		T _C = 25 °C		0.2		1.0		
		T _C = 125 °C	I _R ⁽¹⁾	4	0	5	0	mA

Note

 $^{^{(1)}\,}$ Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT		
Typical thermal resistance from junction to case per diode	$R_{\theta JC}$	1.5	4.5	1.5	°C/W		

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	MBR2545CT-E3/45	1.85	45	50/tube	Tube		
ITO-220AB	MBRF2545CT-E3/45	1.99	45	50/tube	Tube		
TO-263AB	MBRB2545CT-E3/45	1.35	45	50/tube	Tube		
TO-263AB	MBRB2545CT-E3/81	1.35	81	800/reel	Tape and reel		
TO-220AB	MBR2545CT-E3/4W	1.85	4W	50/tube	Tube		
TO-220AB	MBR2545CTHE3/45 (1)	1.85	45	50/tube	Tube		
ITO-220AB	MBRF2545CTHE3/45 (1)	1.99	45	50/tube	Tube		
TO-263AB	MBRB2545CTHE3/45 (1)	1.35	45	50/tube	Tube		
TO-263AB	MBRB2545CTHE3/81 (1)	1.35	81	800/reel	Tape and reel		

Note

⁽¹⁾ AEC-Q101 qualified

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RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

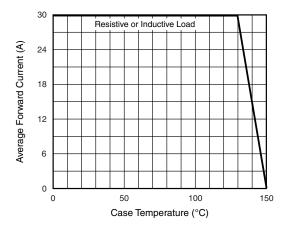


Fig. 1 - Forward Current Derating Curve

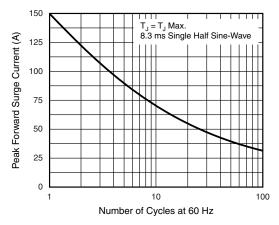


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

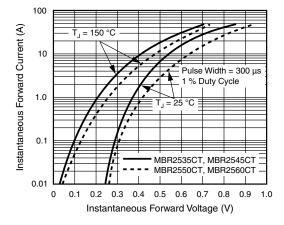


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

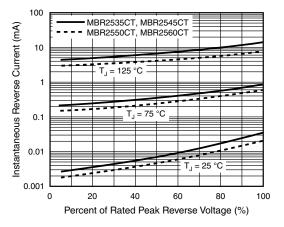


Fig. 4 - Typical Reverse Characteristics Per Diode

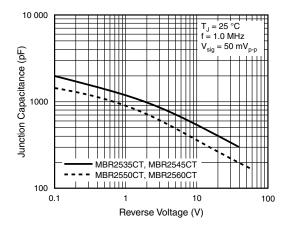


Fig. 5 - Typical Junction Capacitance Per Diode

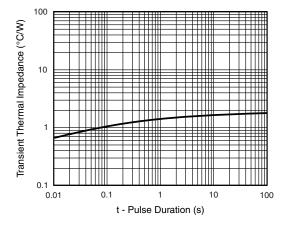


Fig. 6 - Typical Transient Thermal Impedance Per Diode

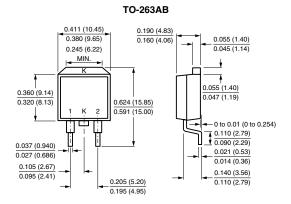


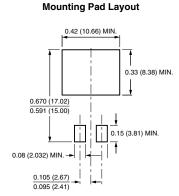
MBR25xxCT, MBRF25xxCT, MBRB25xxCT

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AB ITO-220AB 0.404 (10.26) 0.190 (4.83) 0.415 (10.54) MAX. 0.170 (4.32) 0.185 (4.70) 0.370 (9.40) 0.154 (3.91) 0.110 (2.79) 0.076 (1.93) REF. 0.360 (9.14) 0.148 (3.74) 0.175 (4.44) 0.100 (2.54) 0.055 (1.39) 7° REF. 0.113 (2.87) 0.045 (1.14) 45° REF 0.103 (2.62) 0.135 (3.43) DIA. 0.122 (3.08) DIA. 0.140 (3.56) DIA. 0.125 (3.17) DIA. 7° RÉF 0.145 (3.68) 0.671 (17.04) 0.135 (3.43) 0.600 (15.24 0.580 (14.73) 0.651 (16.54) 0.603 (15.32) 0.635 (16.13) PIN 0.350 (8.89) 0.573 (14.55) 0.625 (15.87) PIN 0.350 (8.89) 0.330 (8.38) 0.330 (8.38) 7° REF. 0.160 (4.06) 1.148 (29.16) 0.191 (4.85) 0.140 (3.56) 1.118 (28.40) 0.171 (4.35) 0.110 (2.79) 0.560 (14.22) 0.530 (13.46) 0.110 (2.79) 0.045 (1.14) 0.057 (1.45) 0.100 (2.54) 0.560 (14.22) 0.530 (13.46 0.057 (1.45) 0.045 (1.14) 0.045 (1.14 0.105 (2.67) 0.105 (2.0., 0.035 (0.90) 0.035 (0.89) 0.025 (0.64) 0.028 (0.71) 0.028 (0.70) 0.104 (2.65) 0.025 (0.64) 0.022 (0.56) 0.015 (0.38) 0.020 (0.51) 0.205 (5.20) 0.096 (2.45) 0.014 (0.36) 0.105 (2.67) 0.095 (2.41) 0.195 (4.95) 0.205 (5.21) 0.195 (4.95)







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